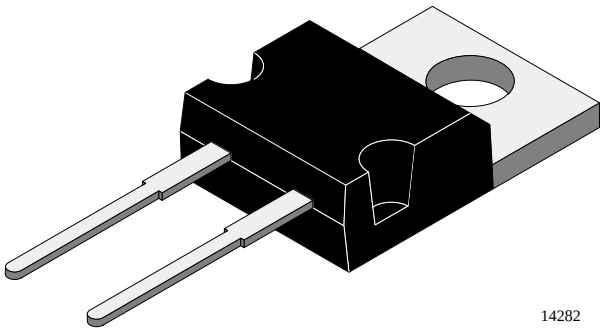
Fast Recovery Silicon Power Rectifier

Features

- Multiple diffusion
- Low switch on power losses
- Good soft recovery behaviour
- Fast forward recovery time
- Fast reverse recovery time
- Low reverse current
- Very good reverse current stability at high temperature
- Low thermal resistance



Applications

Fast rectifiers in S.M.P.S
Freewheeling diodes and snubber diodes in motor control circuits

Absolute Maximum Ratings

T_j = 25°C

Parameter	Test Conditions	Type	Symbol	Value	Unit
Reverse voltage =Repetitive peak reverse voltage			$V_R=V_{RRM}$	1300	V
Peak forward surge current	t_p=10ms, half sinewave		I_{FSM}	50	A
Repetitive peak forward current			I_{FRM}	15	A
Average forward current			I_{FAV}	5	A
Junction and storage temperature range			$T_j=T_{stg}$	–40...+150	°C

Maximum Thermal Resistance

T_j = 25°C

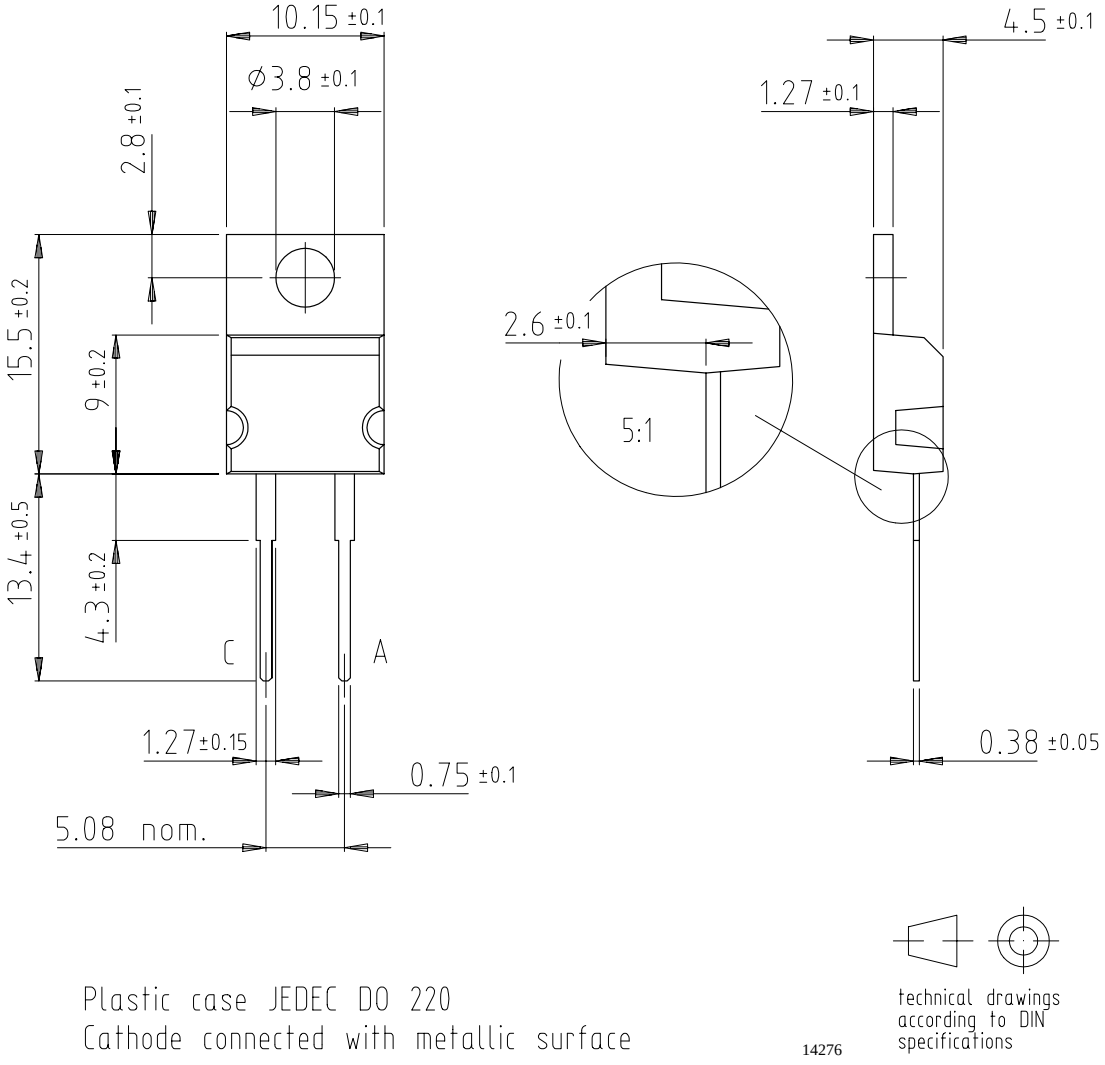
Parameter	Test Conditions	Symbol	Value	Unit
Junction case		R_{thJC}	2.4	K/W
Junction ambient		R_{thJA}	85	K/W

Electrical Characteristics

T_j = 25°C

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Forward voltage	I_F=5A		V_F			1.8	V
	I_F=5A, T_j=100°C		V_F			1.8	V
Reverse current	V_R=V_{RRM}		I_R			10	µA
	V_R=V_{RRM}, T_j=100°C		I_R			0.2	mA
Forward recovery time	I_F=5A, $di_F/dt \leqq 50A/\mu s$		t_{fr}		350		ns
Turn on transient peak voltage			V_{FP}		7		V
Reverse recovery time	I_F=0.5A, I_R=1A, i_R=0.25A		t_{rr}			150	ns

Dimensions in mm



Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.

2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems
   with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively

2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA

3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.
Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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